Organic Solar Cells

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Conjugated (semiconducting) molecules

Abundant: > 70,000 tons/year Non-toxic Low-cost: ~1 $g \rightarrow 17c/m^2$ Stable





Peter Peumans (Stanford Electrical Engineering)

Single semiconductor organic PV cells



The film can be spin cast or evaporated.

High exciton binding energy Low mobility Quantum efficiency < 1 %

Flat bilayer organic PV cells



- Carriers are split at the interface.¹
- They selectively diffuse to the electrodes.²

- Exciton diffusion length ~ 4-20 nm
- Absorption length ~ 100-200 nm

¹C.W. Tang, APL 48 (1986) p. 183.
²B.A. Gregg, J. Phys. Chem. B 107 (2003) p. 4688.

Nanostructured Cells





Excitons are split at interfaces.

Separating the electrons and holes enables the use of low quality materials

January 2005 Materials Research Society Bulletin

Bulk heterojunction PV cells made by casting blends





Heeger et al. Science 270 (1995) p. 1789.



Alivisatos et al., Science 295 (2002) p. 2425

© fabrication is simple

☺ not all excitons reach at interface

 $\ensuremath{\mathfrak{S}}$ there are deadends

Processes in bulk heterojunction PV cells



Ordered bulk heterojunctions



- Almost all excitons can be split
- No deadends
- Polymer chains can be aligned

- Easy to model
- Semiconductors can be changed without changing the geometry.



G.D. Stucky et al. *Chem. Mater.* 14 (2002) p. 3284.C. Sanchez et al. *JACS* 125 (2003) p. 9770.

Mesoporous titania films



- © Film thickness can be varied from 50 300 nm
- © Pore radius: 4 nm in the plane and 2-3 nm perpendicular to the plane
- © Film quality is very high
- ☺ Pores are not straight

Melt infiltration



Adv.Func.Mat., 13 (2003) p. 301

Photovoltaic cells



Green: Solid (nonporous) titania

App. Phys. Lett. 83 (2003) 3380

Photocurrent is only generated at the top



App. Phys. Lett. 83 (2003) 3380

A path to 20 % efficiency

20 % efficiency can be achieve if

 We find a method for patterning 20-nm-wide straight holes that are 200 nm deep in a suitable semiconductor.



2.) We reduce the bandgap to absorb more light.

3.) The energy loss associated with electron transfer is reduced.

4.) The charge carrier mobility is improved and the interface is engineered to almost eliminate recombination.

5.) We stack cells of different bandgaps to harvest more of the solar energy.

Review: Coakley and McGehee, Chemistry of Materials, 16 (2004) 4533-42.